

Micropower, Low Voltage Comparator with 400mV Reference

FEATURES

- Internal 400mV Reference
- Total Threshold Error: $\pm 1.25\%$ Max at 25°C
- Wide Supply Range: 1.4V to 18V
- Input and Output Operate to 36V
- Specified for -40°C to 125°C Temperature Range
- Low Quiescent Current: 6.5µA Typ at 5V
- Internal Hysteresis: 6.5mV Typ
- Low Input Bias Current: ± 10 nA Max
- Over-The-Top® Input also Includes Ground
- Open-Collector Output Allows Level Translation
- Choice of Input Polarities: LT6703-2/LT6703-3/LT6703HV-2/LT6703HV-3
- Available in 2mm × 2mm DFN and Low Profile (1mm) SOT-23 (ThinSOT™) Packages

APPLICATIONS

- Battery-Powered System Monitoring
- Threshold Detectors
- Window Comparators
- Relay Driving
- Industrial Control Systems
- Handheld Instruments
- Automotive Monitor and Controls

DESCRIPTION

The LT®6703-2/LT6703-3/LT6703HV-2/LT6703HV-3 combine a micropower, low voltage comparator with a 400mV reference in a tiny DFN package. Operating with supplies from 1.4V up to 18V, these devices draw only 6.5µA, making them ideal for low voltage system monitoring. Hysteresis is included in the comparator, ensuring stable operation.

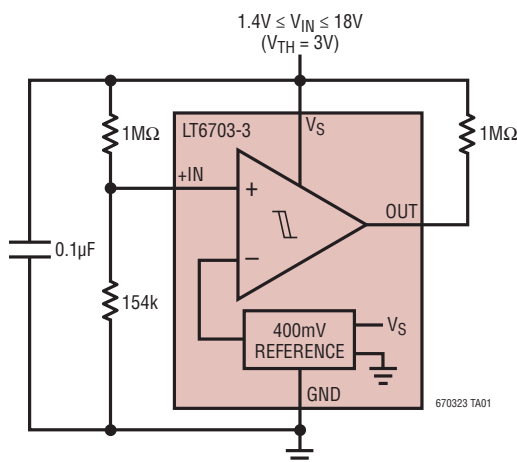
The comparator has one input available externally while the other input is connected internally to the reference. The comparator output is open collector and the output load can be referred to any voltage up to 18V (36V for LT6703HV) independent of supply voltage. The output stage has a guaranteed current sink capability of more than 5mA over temperature.

The two versions of this part differ by the polarity of the available comparator input. The LT6703-2/LT6703HV-2 has an inverting input and the LT6703-3/LT6703HV-3 has a noninverting input. Both versions are offered in commercial, industrial and automotive temperature ranges.

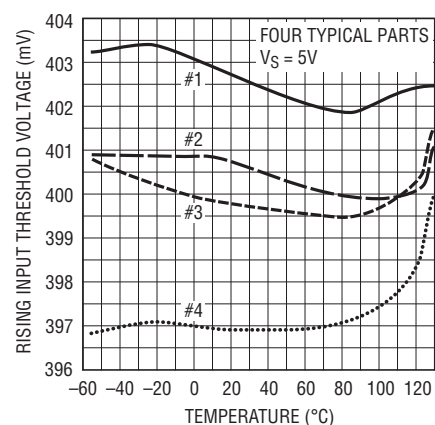
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TYPICAL APPLICATION

Micropower Supply Voltage Monitor



Rising Input Threshold Voltage vs Temperature



670323 TA01b

670323fd

LT6703-2/LT6703-3 LT6703HV-2/LT6703HV-3

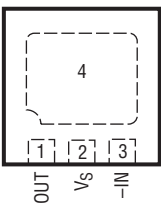
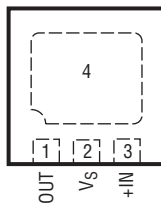
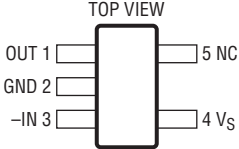
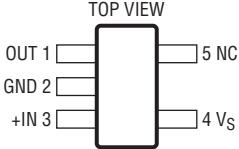
ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V_S to GND) 18.5V
 Input Voltage (+IN, -IN)
 (Note 3)..... 18.5V to (GND - 0.3V)
 LT6703HV 40V to (GND - 0.3V)
 Output Voltage (OUT)..... 18.5V to (GND - 0.3V)
 LT6703HV 40V to (GND - 0.3V)
 Output Short-Circuit Duration (Note 2) Indefinite
 Input Current (Note 3)..... -10mA

Operating Temperature Range (Note 4)
 LT6703C-2/-3/LT6703HVC-2/-3 -40°C to 85°C
 LT6703I-2/-3/LT6703HVI-2/-3 -40°C to 85°C
 LT6703H-2/-3/LT6703HVH-2/-3 -40°C to 125°C
 Specified Temperature Range (Note 5)
 LT6703C-2/-3/LT6703HVC-2/-3 0°C to 70°C
 LT6703I-2/-3/LT6703HVI-2/-3 -40°C to 85°C
 LT6703H-2/-3/LT6703HVH-2/-3 -40°C to 125°C
 Maximum Junction Temperature..... 125°C
 Storage Temperature Range..... -65°C to 125°C
 Lead Temperature (Soldering, 10 sec) 300°C

PIN CONFIGURATION

<p>LT6703-2</p> <p>TOP VIEW</p>  <p>DC PACKAGE 3-LEAD (2mm × 2mm) PLASTIC DFN $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 102^{\circ}\text{C/W}$ EXPOSED PAD (PIN 4) IS GND, MUST BE SOLDERED TO PCB</p>	<p>LT6703-3</p> <p>TOP VIEW</p>  <p>DC PACKAGE 3-LEAD (2mm × 2mm) PLASTIC DFN $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 102^{\circ}\text{C/W}$ EXPOSED PAD (PIN 4) IS GND, MUST BE SOLDERED TO PCB</p>
<p>LT6703HV-2</p> <p>TOP VIEW</p>  <p>S5 PACKAGE 5-LEAD PLASTIC TSOT-23 $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 250^{\circ}\text{C/W}$</p>	<p>LT6703HV-3</p> <p>TOP VIEW</p>  <p>S5 PACKAGE 5-LEAD PLASTIC TSOT-23 $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 250^{\circ}\text{C/W}$</p>

ORDER INFORMATION

Lead Free Finish

TAPE AND REEL (MINI)	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT6703CDC-2#TRMPBF	LT6703CDC-2#TRPBF	LCWP	3-Lead (2mm × 2mm) Plastic DFN	0°C to 70°C
LT6703IDC-2#TRMPBF	LT6703IDC-2#TRPBF	LCWP	3-Lead (2mm × 2mm) Plastic DFN	-40°C to 85°C
LT6703HDC-2#TRMPBF	LT6703HDC-2#TRPBF	LCWP	3-Lead (2mm × 2mm) Plastic DFN	-40°C to 125°C
LT6703CDC-3#TRMPBF	LT6703CDC-3#TRPBF	LCTW	3-Lead (2mm × 2mm) Plastic DFN	0°C to 70°C
LT6703IDC-3#TRMPBF	LT6703IDC-3#TRPBF	LCTW	3-Lead (2mm × 2mm) Plastic DFN	-40°C to 85°C
LT6703HDC-3#TRMPBF	LT6703HDC-3#TRPBF	LCTW	3-Lead (2mm × 2mm) Plastic DFN	-40°C to 125°C
LT6703HVCS5-2#TRMPBF	LT6703HVCS5-2#TRPBF	LTDMM	5-Lead Plastic TSOT-23	0°C to 70°C
LT6703HVIS5-2#TRMPBF	LT6703HVIS5-2#TRPBF	LTDMM	5-Lead Plastic TSOT-23	-40°C to 85°C
LT6703HVHS5-2#TRMPBF	LT6703HVHS5-2#TRPBF	LTDMM	5-Lead Plastic TSOT-23	-40°C to 125°C
LT6703HVCS5-3#TRMPBF	LT6703HVCS5-3#TRPBF	LTDMP	5-Lead Plastic TSOT-23	0°C to 70°C
LT6703HVIS5-3#TRMPBF	LT6703HVIS5-3#TRPBF	LTDMP	5-Lead Plastic TSOT-23	-40°C to 85°C
LT6703HVHS5-3#TRMPBF	LT6703HVHS5-3#TRPBF	LTDMP	5-Lead Plastic TSOT-23	-40°C to 125°C

TRM = 500 pieces. *Temperature grades are identified by a label on the shipping container.

Consult LTC Marketing for parts specified with wider operating temperature ranges.

Consult LTC Marketing for information on lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreel/>

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ (LT6703-2/LT6703-3) unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V$ Swing, $V_S = 5V$	395	400	405	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V$ Swing, $V_S = 5V$	387	393.5	400	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V, R_L = 100k, V_O = 2V$ Swing	3.5	6.5	9.5	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V, V_{IN} = V_S$ $V_S = 1.4V, V_{IN} = 18V$ $V_S = 1.4V, 18V, V_{IN} = 0.1V$		± 0.01 ± 0.01 ± 4	± 10 ± 10 ± 10	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V, I_{OUT} = 5mA$		70	200	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V, V_{OUT} = V_S, V_{IN} = 40mV$ Overdrive $V_S = 1.4V, V_{OUT} = 18V, V_{IN} = 40mV$ Overdrive		0.01 0.01	0.8 0.8	μA μA
$t_{PD(HL)}$	High-to-Low Propagation Delay	$V_S = 5V, 10mV$ Input Overdrive, $R_L = 10k$, $V_{OL} = 400mV$		18		μs
$t_{PD(LH)}$	Low-to-High Propagation Delay	$V_S = 5V, 10mV$ Input Overdrive, $R_L = 10k$, $V_{OH} = 0.9 \cdot V_S$		29		μs
t_r	Output Rise Time	$V_S = 5V, 10mV$ Input Overdrive, $R_L = 10k$ $V_O = (0.1 \text{ to } 0.9) \cdot V_S$		2.2		μs
t_f	Output Fall Time	$V_S = 5V, 10mV$ Input Overdrive, $R_L = 10k$ $V_O = (0.1 \text{ to } 0.9) \cdot V_S$		0.22		μs
I_S	Supply Current	No Load Current, $V_S = 5V$		6.5	11	μA

LT6703-2/LT6703-3

LT6703HV-2/LT6703HV-3

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the temperature range of $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, (LT6703C-2/LT6703C-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 392.5		407.5	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 384.5		402.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V, R_L = 100k, V_O = 2V \text{ Swing}$	● 3		11	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V, V_{IN} = V_S$ $V_S = 1.4V, V_{IN} = 18V$ $V_S = 1.4V, 18V, V_{IN} = 0.1V$	●		±15 ±15 ±15	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V, I_{OUT} = 5mA$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V, V_{OUT} = V_S, V_{IN} = 40mV \text{ Overdrive}$ $V_S = 1.4V, V_{OUT} = 18V, V_{IN} = 40mV \text{ Overdrive}$	●		1 1	μA μA
I_S	Supply Current	No Load Current, $V_S = 5V$	●		14	μA

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, (LT6703I-2/LT6703I-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 392		408	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 383.5		403.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V, R_L = 100k, V_O = 2V \text{ Swing}$	● 2		11.5	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V, V_{IN} = V_S$ $V_S = 1.4V, V_{IN} = 18V$ $V_S = 1.4V, 18V, V_{IN} = 0.1V$	●		±15 ±15 ±15	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V, I_{OUT} = 5mA$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V, V_{OUT} = V_S, V_{IN} = 40mV \text{ Overdrive}$ $V_S = 1.4V, V_{OUT} = 18V, V_{IN} = 40mV \text{ Overdrive}$	●		1 1	μA μA
I_S	Supply Current	No Load Current, $V_S = 5V$	●		15	μA

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$, (LT6703H-2/LT6703H-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 392		410	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k, V_O = 2V \text{ Swing}, V_S = 5V$	● 382.5		404.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V, R_L = 100k, V_O = 2V \text{ Swing}$	● 2		13.5	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V, V_{IN} = V_S$ $V_S = 1.4V, V_{IN} = 18V$ $V_S = 1.4V, 18V, V_{IN} = 0.1V$	●		±45 ±45 ±50	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V, I_{OUT} = 5mA$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V, V_{OUT} = V_S, V_{IN} = 40mV \text{ Overdrive}$ $V_S = 1.4V, V_{OUT} = 18V, V_{IN} = 40mV \text{ Overdrive}$	●		1 1	μA μA
I_S	Supply Current	No Load Current, $V_S = 5V$	●		17	μA

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, (LT6703HV-2/LT6703HV-3) unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	395	400	405	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	387	393.5	400	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V$, $R_L = 100k$, $V_O = 2V$ Swing	3.5	6.5	9.5	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V$, $V_{IN} = V_S$ $V_S = 1.4V$, $V_{IN} = 18V, 36V$ $V_S = 1.4V, 18V$, $V_{IN} = 0.1V$		± 0.01 ± 0.01 ± 4	± 10 ± 10 ± 10	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V$, $I_{OUT} = 5mA$		70	200	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V$, $V_{OUT} = V_S$, $V_{IN} = 40mV$ Overdrive $V_S = 18V$, $V_{OUT} = 18V$, (36V, $R_L = 100k$), $V_{IN} = 40mV$ Overdrive		0.01 0.01	0.8 0.8	μA μA
$t_{PD(HL)}$	High-to-Low Propagation Delay	$V_S = 5V$, 10mV Input Overdrive, $R_L = 10k$, $V_{OL} = 400mV$		18		μs
$t_{PD(LH)}$	Low-to-High Propagation Delay	$V_S = 5V$, 10mV Input Overdrive, $R_L = 10k$, $V_{OH} = 0.9 \cdot V_S$		29		μs
t_r	Output Rise Time	$V_S = 5V$, 10mV Input Overdrive, $R_L = 10k$ $V_O = (0.1 \text{ to } 0.9) \cdot V_S$		2.2		μs
t_f	Output Fall Time	$V_S = 5V$, 10mV Input Overdrive, $R_L = 10k$ $V_O = (0.1 \text{ to } 0.9) \cdot V_S$		0.22		μs
I_S	Supply Current	No Load Current, $V_S = 5V$		6.5	11	μA

The ● denotes the specifications which apply over the temperature range of $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, (LT6703HVC-2/LT6703HVC-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	●	392.5	407.5	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	●	384.5	402.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V$, $R_L = 100k$, $V_O = 2V$ Swing	●	3	11	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V$, $V_{IN} = V_S$ $V_S = 1.4V$, $V_{IN} = 18V, 36V$ $V_S = 1.4V, 18V$, $V_{IN} = 0.1V$	● ● ●		± 15 ± 15 ± 15	nA nA nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5V$, $I_{OUT} = 5mA$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4V, 18V$, $V_{OUT} = V_S$, $V_{IN} = 40mV$ Overdrive $V_S = 18V$, $V_{OUT} = 18V$, (36V, $R_L = 100k$), $V_{IN} = 40mV$ Overdrive	● ●		1 1	μA μA
I_S	Supply Current	No Load Current, $V_S = 5V$	●		14	μA

The ● denotes the specifications which apply over the temperature range of $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$, (LT6703HVI-2/LT6703HVI-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	●	392	408	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100k$, $V_O = 2V$ Swing, $V_S = 5V$	●	383.5	403.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5V$, $R_L = 100k$, $V_O = 2V$ Swing	●	2	11.5	mV
I_B	Input Bias Current	$V_S = 1.4V, 18V$, $V_{IN} = V_S$ $V_S = 1.4V$, $V_{IN} = 18V, 36V$ $V_S = 1.4V, 18V$, $V_{IN} = 0.1V$	● ● ●		± 15 ± 15 ± 15	nA nA nA

LT6703-2/LT6703-3

LT6703HV-2/LT6703HV-3

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, (LT6703HVI-2/LT6703HVI-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5\text{V}$, $I_{OUT} = 5\text{mA}$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4\text{V}, 18\text{V}$, $V_{OUT} = V_S$, $V_{IN} = 40\text{mV}$ Overdrive $V_S = 18\text{V}$, $V_{OUT} = 18\text{V}$, (36V, $R_L = 100\text{k}$), $V_{IN} = 40\text{mV}$ Overdrive	●		1	μA
I_S	Supply Current	No Load Current, $V_S = 5\text{V}$	●		15	μA

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$, (LT6703HVH-2/LT6703HVH-3) unless otherwise specified (Notes 4, 5).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{TH(R)}$	Rising Input Threshold Voltage (Note 6)	$R_L = 100\text{k}$, $V_O = 2\text{V}$ Swing, $V_S = 5\text{V}$	●	392	410	mV
$V_{TH(F)}$	Falling Input Threshold Voltage (Note 6)	$R_L = 100\text{k}$, $V_O = 2\text{V}$ Swing, $V_S = 5\text{V}$	●	382.5	404.5	mV
HYS	$HYS = V_{TH(R)} - V_{TH(F)}$	$V_S = 5\text{V}$, $R_L = 100\text{k}$, $V_O = 2\text{V}$ Swing	●	2	13.5	mV
I_B	Input Bias Current	$V_S = 1.4\text{V}, 18\text{V}$, $V_{IN} = V_S$ $V_S = 1.4\text{V}$, $V_{IN} = 18\text{V}, 36\text{V}$ $V_S = 1.4\text{V}, 18\text{V}$, $V_{IN} = 0.1\text{V}$	●		± 45	nA
V_{OL}	Output Low Voltage	10mV Input Overdrive, $V_S = 5\text{V}$, $I_{OUT} = 5\text{mA}$	●		250	mV
I_{OFF}	Output Leakage Current	$V_S = 1.4\text{V}, 18\text{V}$, $V_{OUT} = V_S$, $V_{IN} = 40\text{mV}$ Overdrive $V_S = 18\text{V}$, $V_{OUT} = 18\text{V}$, (36V, $R_L = 100\text{k}$), $V_{IN} = 40\text{mV}$ Overdrive	●		1	μA
I_S	Supply Current	No Load Current, $V_S = 5\text{V}$	●		17.0	μA

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.

Note 3: The inputs are protected by ESD diodes to the ground pin. If the input voltage exceeds -0.3V below ground, the input current should be limited to less than 10mA.

Note 4: The LT6703C-2/-3/LT6703HVC-2/-3, and LT6703I-2/-3/LT6703HVI-2/-3 are guaranteed functional over the operating temperature range of -40°C to 85°C .

The LT6703H-2/-3/LT6703HVH-2/-3, is guaranteed functional over the operating temperature range of -40°C to 125°C .

Note 5: The LT6703C-2/-3/LT6703HVC-2/-3, are guaranteed to meet the specified performance from 0°C to 70°C . The LT6703C-2/-3/LT6703HVC-2/-3 are designed, characterized and expected to meet specified performance from -40°C to 85°C but are not tested or QA sampled at these temperatures. The LT6703I-2/-3/LT6703HVI-2/-3, are guaranteed to meet specified performance from -40°C to 85°C . The LT6703H-2/-3/LT6703HVH-2/-3, is guaranteed to meet specified performance from -40°C to 125°C .

Note 6: V_{TH} defines the threshold voltage of the comparator and combines the effect of offset and reference accuracy.

PIN FUNCTIONS

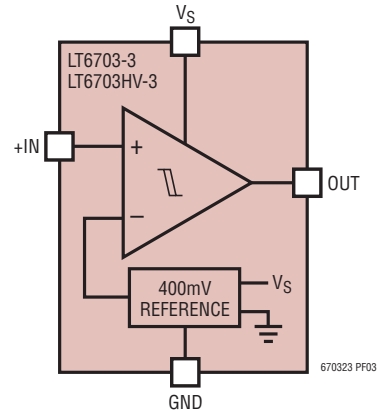
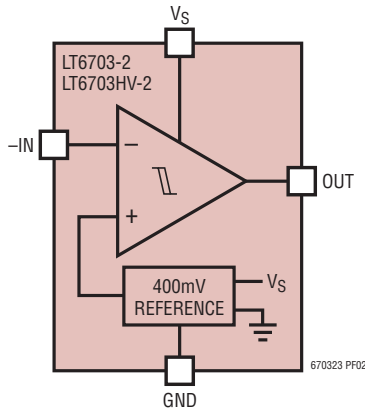
OUT: Open-Collector Output of Comparator. This pin provides drive for up to 40mA of load current. Off-state voltage may be as high as 18V (36V for LT6703HV) above GND, regardless of V_S used.

GND: Ground. This pin is also the low side return of the internal 400mV reference.

IN: External Input for Comparator. The voltage on this pin can range from -0.3V to 18V (36V for LT6703HV) with respect to GND regardless of V_S used. The input is noninverting for the LT6703-3/LT6703HV-3, and inverting for the LT6703-2/LT6703HV-2. The other comparator input is internally connected to the 400mV reference.

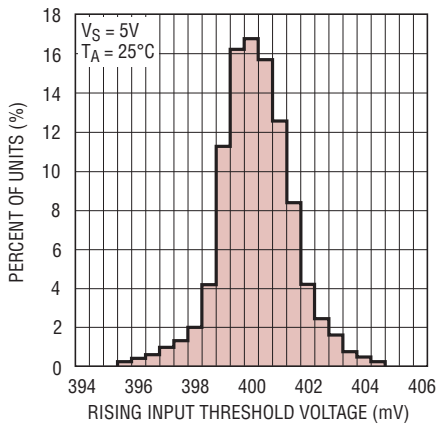
V_S : Supply Voltage. The parts are characterized for operation with $1.4\text{V} \leq V_S \leq 18\text{V}$ with respect to GND.

PIN FUNCTIONS



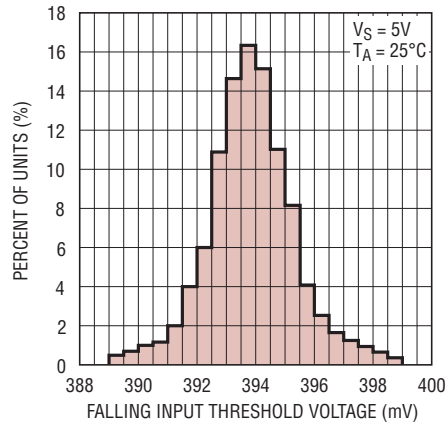
TYPICAL PERFORMANCE CHARACTERISTICS

Distribution of Rising Input Threshold Voltage



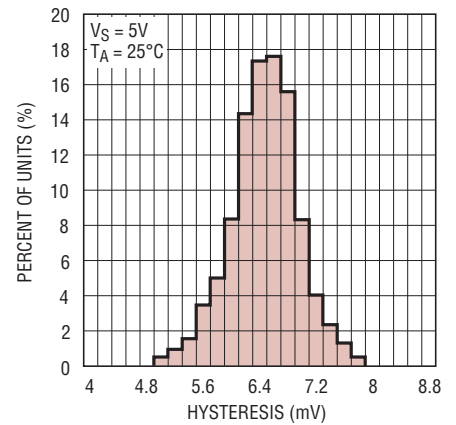
670323 G01

Distribution of Falling Input Threshold Voltage



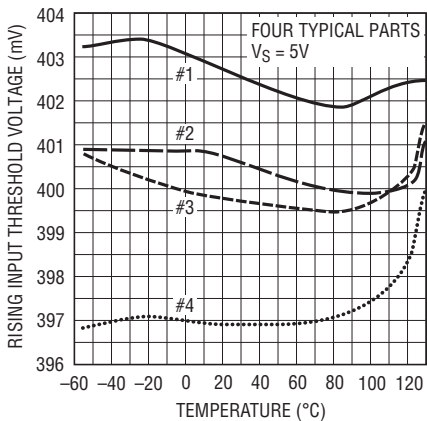
670323 G02

Distribution of Hysteresis



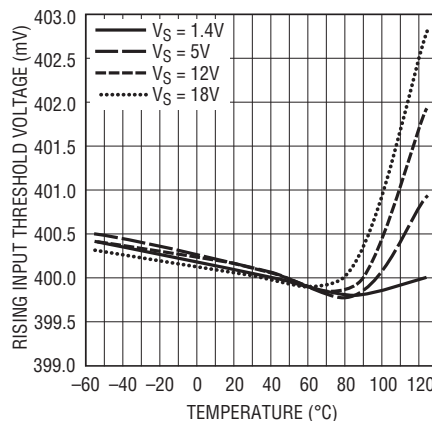
670323 G03

Rising Input Threshold Voltage vs Temperature



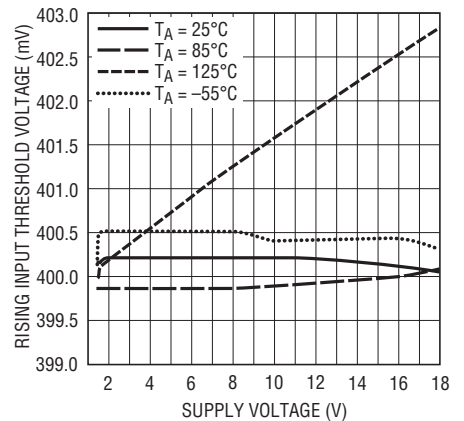
670323 G04

Rising Input Threshold Voltage vs Temperature



670323 G05

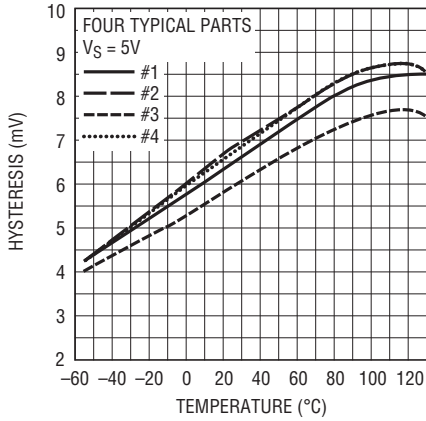
Rising Input Threshold Voltage vs Supply Voltage



670323 G06

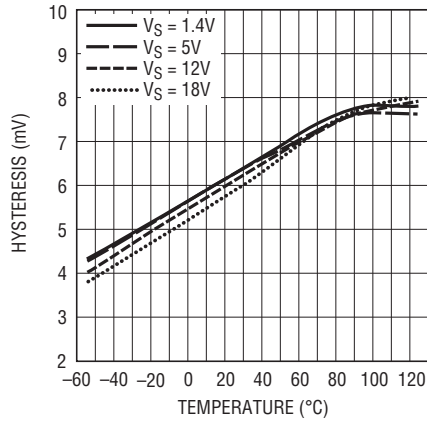
TYPICAL PERFORMANCE CHARACTERISTICS

Hysteresis vs Temperature



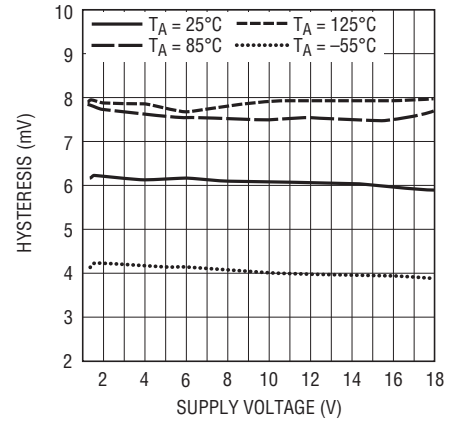
670323 G07

Hysteresis vs Temperature



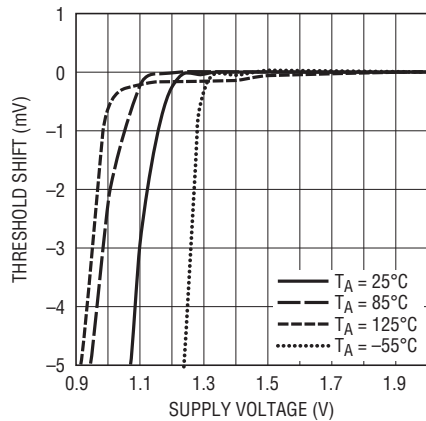
670323 G08

Hysteresis vs Supply Voltage



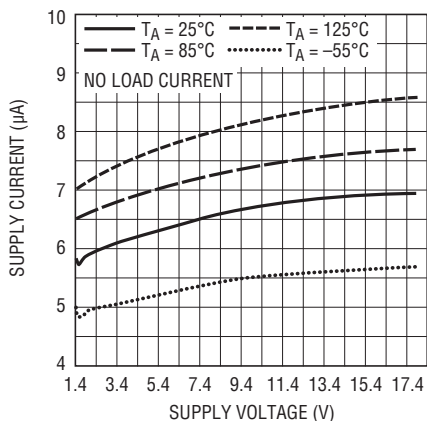
670323 G09

Minimum Supply Voltage



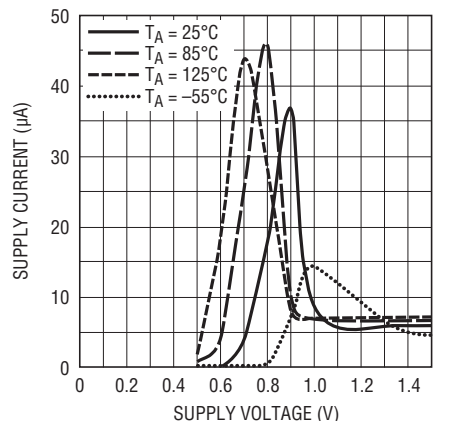
670323 G10

Quiescent Supply Current vs Supply Voltage



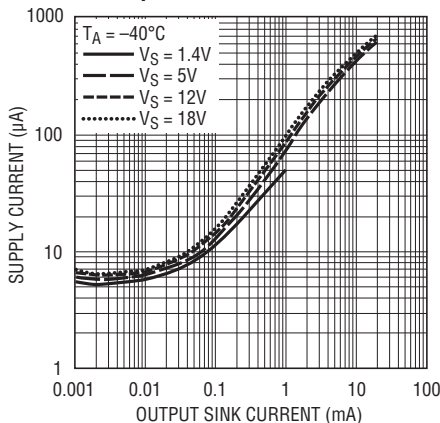
670323 G11

Start-Up Supply Current



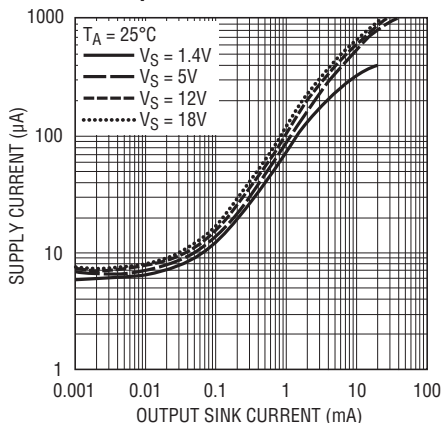
670323 G12

Supply Current vs Output Sink Current



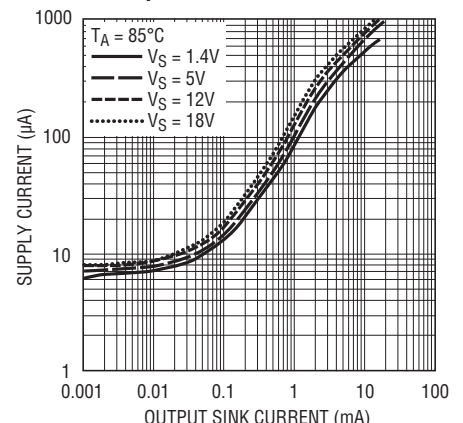
670323 G13

Supply Current vs Output Sink Current



670323 G14

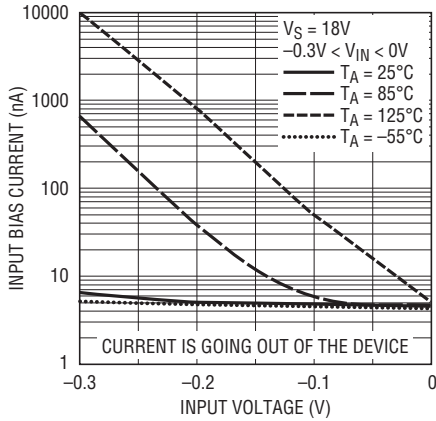
Supply Current vs Output Sink Current



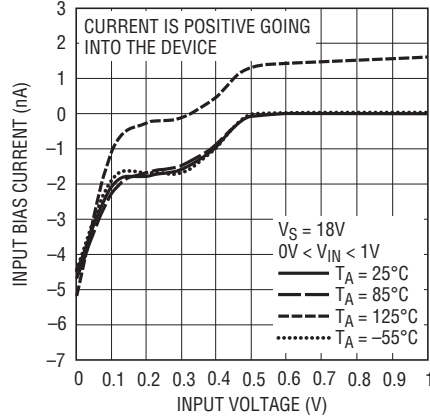
670323 G15

TYPICAL PERFORMANCE CHARACTERISTICS

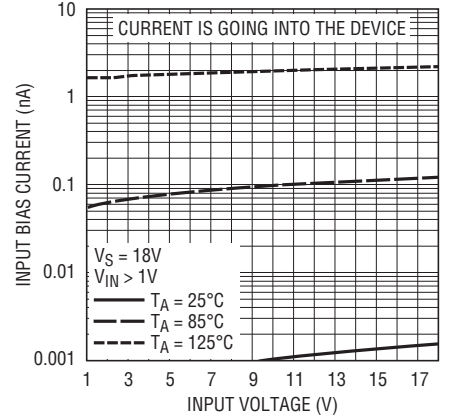
Below Ground Input Bias Current



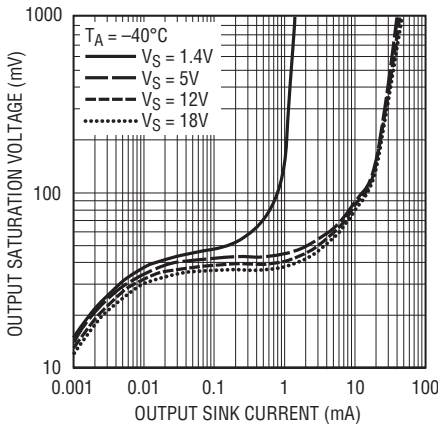
Low Level Input Bias Current



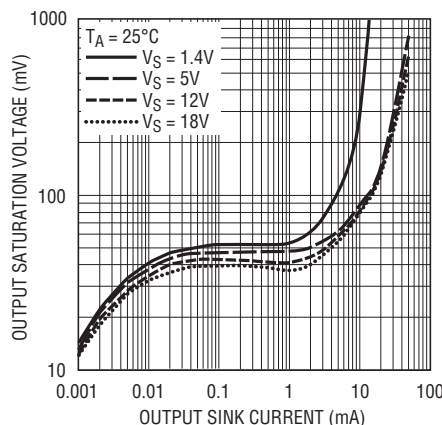
High Level Input Bias Current



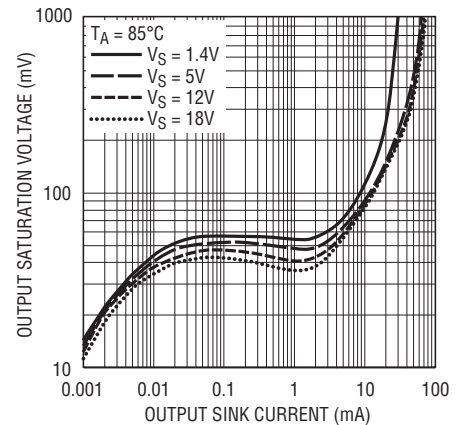
Output Saturation Voltage vs Output Sink Current



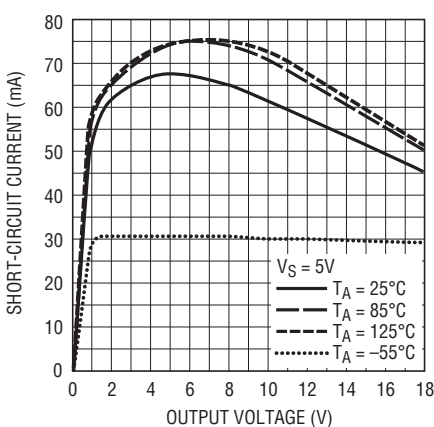
Output Saturation Voltage vs Output Sink Current



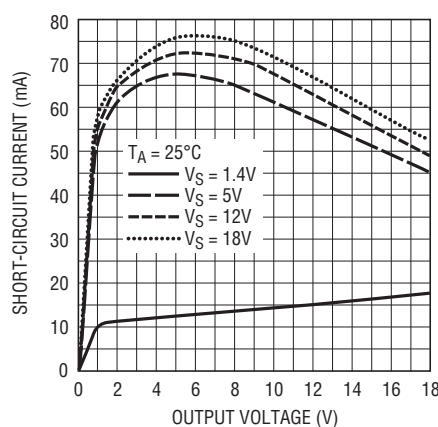
Output Saturation Voltage vs Output Sink Current



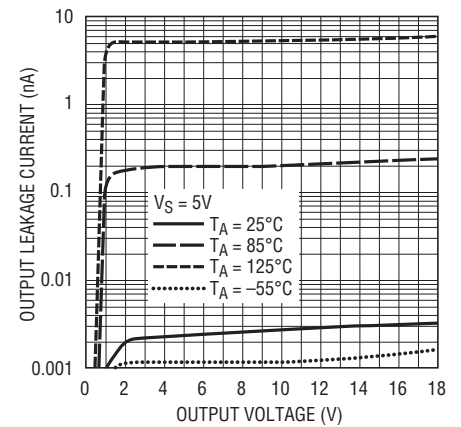
Output Short-Circuit Current



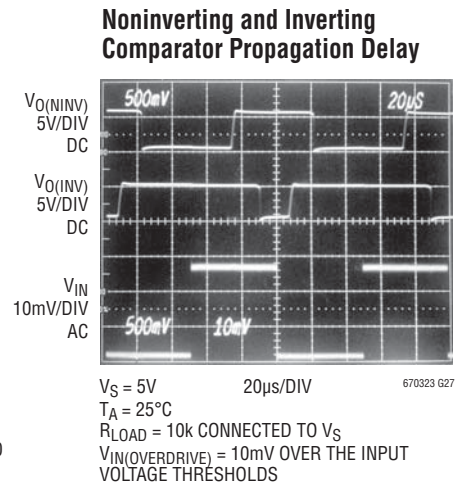
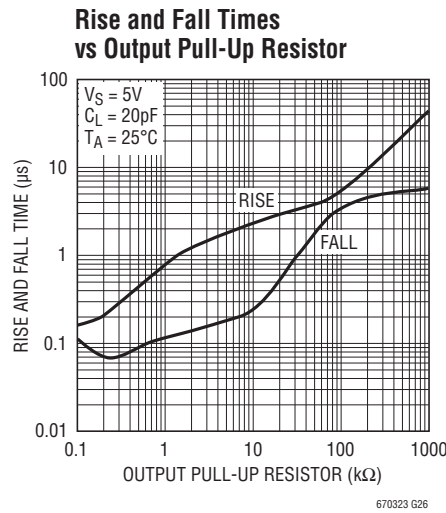
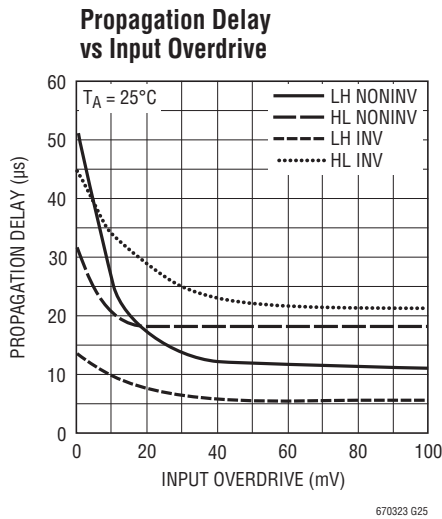
Output Short-Circuit Current



Output Leakage Current

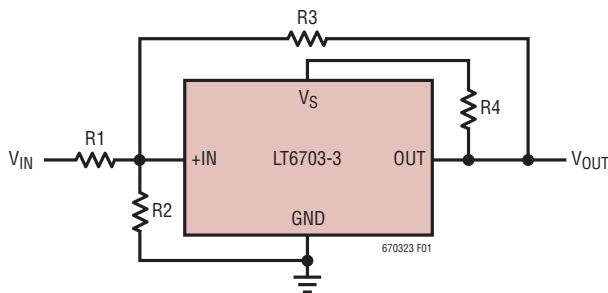


TYPICAL PERFORMANCE CHARACTERISTICS



APPLICATIONS INFORMATION

The LT6703-2/LT6703-3/LT6703HV-2/LT6703HV-3 devices are micropower comparators with a built-in 400mV reference. Features include wide supply voltage range (1.4V to 18V), Over-The-Top input and output range, 2% accurate rising input threshold voltage and 6.5mV typical built-in hysteresis.



THRESHOLD EQUATIONS:

$$V_{IN} \text{ (L TO H)} = (400\text{mV}) \cdot (R1) \cdot \left(\frac{1}{R1} + \frac{1}{R2} + \frac{1}{R3} \right)$$

$$V_{IN} \text{ (H TO L)} = (393\text{mV}) \cdot (R1) \cdot \left(\frac{1}{R1} + \frac{1}{R2} + \frac{1}{R3 + R4} \right) - \left(\frac{V_S \cdot R1}{R3 + R4} \right)$$

Figure 1. Additional Hysteresis Circuit

Internal Reference

Each comparator has one input available externally. The two versions of the part differ by the polarity of the available input (i.e., inverting or noninverting). The other comparator input is connected internally to the 400mV reference. The rising input threshold voltage of the comparator is designed to be equal to that of the reference (i.e., $\approx 400\text{mV}$). The reference voltage is established with respect to the device GND connection.

Hysteresis

Each comparator has built-in 6.5mV (typical) of hysteresis to simplify designs, to insure stable operation in the presence of noise at the inputs, and to reject supply rail noise that might be induced by state change load transients. The hysteresis is designed such that the falling input threshold voltage is nominally 393.5mV. External positive feedback circuitry can be employed to increase effective hysteresis if desired, but such circuitry will provide an apparent effect on both the rising and falling input thresholds (the actual internal thresholds remain unaffected).

APPLICATIONS INFORMATION

Comparator Input

The comparator input can range from ground to 18V (36V for LT6703HV), regardless of the supply voltage used. The typical input current for inputs well above the threshold (i.e., >800mV) is a few pA leaking into the input. With decreasing input voltage, a small bias current begins to be drawn out of the input, reaching a few nA when at ground potential. The input may be forced 100mV below ground without causing an improper output, though some additional bias current will begin to flow from the ESD input protection diode. Inputs driven further negative than 100mV below ground will not cause damage provided the current is limited to 10mA.

Comparator Output

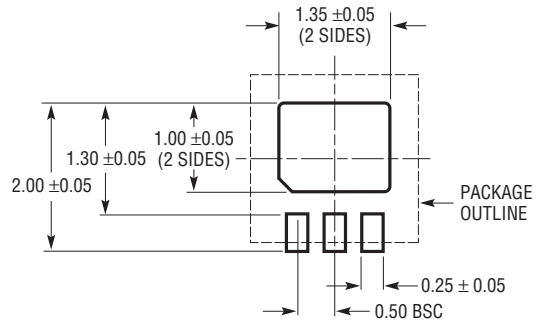
The comparator output is open collector and capable of sinking 40mA typical. Load currents are directed out of the GND pin of the part. The output off-state voltage may range between -0.3V and 18V (36V for LT6703HV) with respect to ground, regardless of the supply voltage used. When the output high state bias voltage is above 18V, a 100k minimum pull-up resistor is required and no total load capacitor greater than 100nF should be used. If the output high state is above 18V, caution has to be taken to prevent a short from the output directly to the bias voltage, even if the output is in the off state. As with any open-collector device, the outputs of multiple comparators may be tied together to implement wire-AND logic functions.

Power Supplies

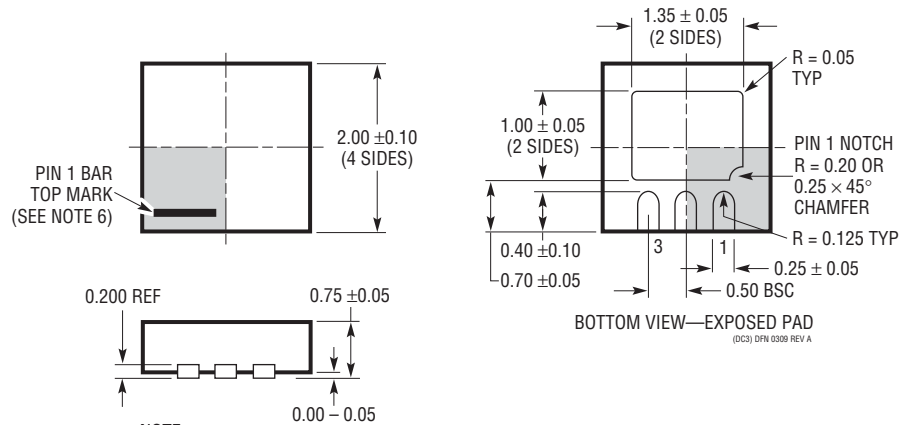
The comparator circuitry operates from a single 1.4V to 18V supply. A minimum 0.1 μF bypass capacitor is required between the V_S pin and GND. When an output load is connected to the supply rail near the part and the output is sinking more than 5mA, a 1 μF bypass capacitor is recommended. In instances where the supply is relatively “soft” (such as with small batteries) and susceptible to load steps, an additional 47 Ω series decoupling resistor can further improve isolation of supply transients from the V_S pin.

PACKAGE DESCRIPTION

DC Package
3-Lead Plastic DFN (2mm × 2mm)
 (Reference LTC DWG # 05-08-1717 Rev A)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS

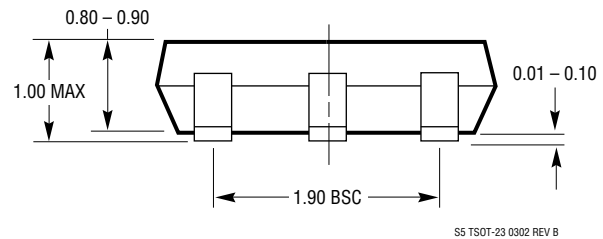
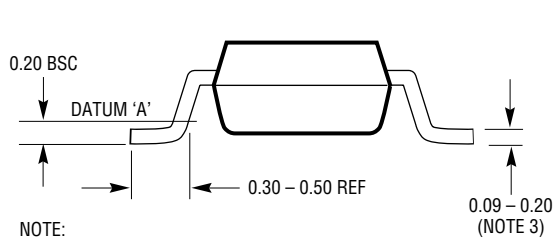
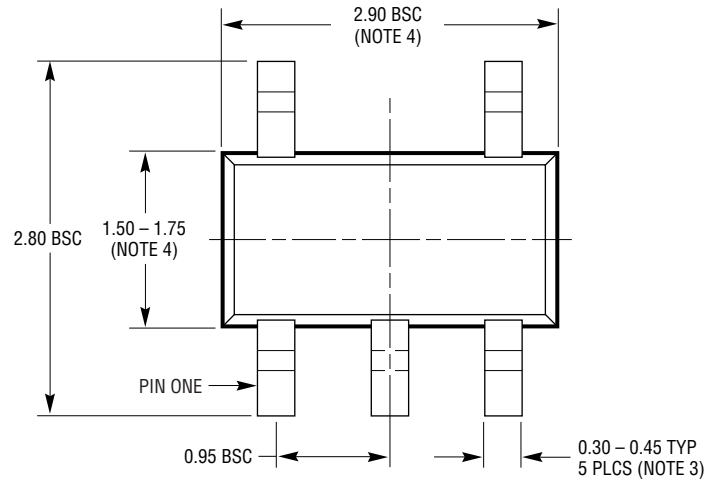
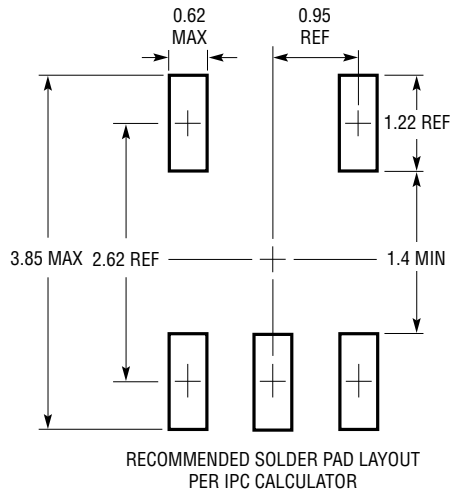


NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (W-TBD)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

PACKAGE DESCRIPTION

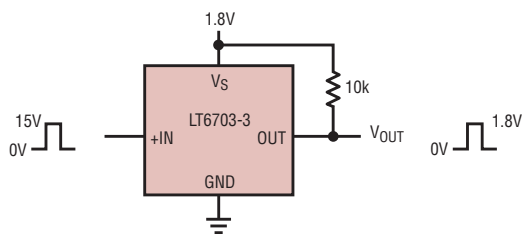
S5 Package
5-Lead Plastic TSOT-23
 (Reference LTC DWG # 05-08-1635 Rev B)



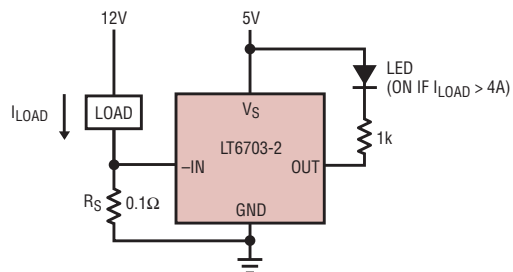
- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
 2. DRAWING NOT TO SCALE
 3. DIMENSIONS ARE INCLUSIVE OF PLATING
 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
 6. JEDEC PACKAGE REFERENCE IS MO-193

S5 TSOT-23 0302 REV B

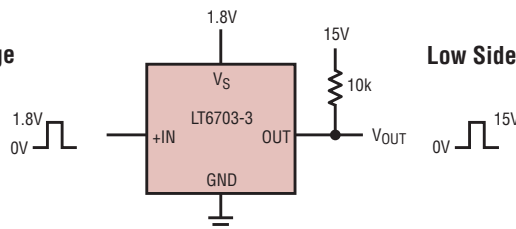
TYPICAL APPLICATIONS



**Level Translator
 High Voltage to Low Voltage**



Low Side Current Sense Alarm



**Level Translator
 Low Voltage to High Voltage**

670323 TA02

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1017/LT1018	Micropower Dual Comparator	1.1V (Min) Supply Voltage, $\pm 1.4\text{mV}$ (Max) Input Offset
LTC1441/LTC1442	Micropower Dual Comparator with 1% Reference	1.182 $\pm 1\%$ Reference, $\pm 10\text{mV}$ (Max) Input Offset
LTC1998	Micropower Comparator for Battery Monitoring	2.5 μA Typ Supply Current, Adjustable Threshold and Hysteresis
LT6700	Dual Micropower Comparator with 400mV Reference	1.4V to 18V Supply Voltage, 6.5 μA Typical Supply Current

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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

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